

# ECONAL **Electronic Components and Logistics**

**ECOMAL** Europe GmbH



# LOW-SIDE GATE DRIVERS



IXYS Integrated Circuits offers powerful families of ultra-fast Low-Side Gate Drivers for MOSFETs and IGBTs, with a large mix of logic configurations, packaging, and drive current capabilities. Five of these devices are AEC-Q100 qualified.

Single-output and dual-output low-side driver ICs include selectable options for logic combinations. The range of current ratings offered is the broadest available, extending to 30A peak, which is the LARGEST PEAK DRIVE CURRENT capability for an integrated driver on the market.

In all series devices, internal circuitry eliminates cross conduction and current "shoot-through," and the driver is virtually immune to latch up.

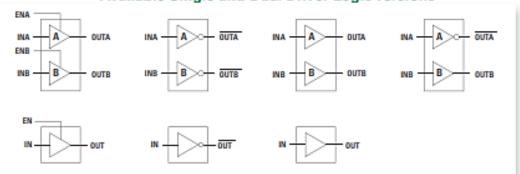
#### Features & Benefits

- 1.5A to 30A peak source/ sink drive current
- Wide operating voltage range up to 35V
- -40°C to +125°C extended operating temperature range
- Logic input withstands negative swing of up to –5V
- Dual drivers have matched rise and fall times
- Low propagation delay time
- Low output impedance

### Applications

- Efficient power MOSFET and IGBT switching
- Switch mode power supplies
- Motor controls
- DC to DC converters
- Class-D switching amplifiers
- Pulse transformer driver

#### **Available Single and Dual Driver Logic Versions**





# HIGH-SIDE AND LOW-SIDE GATE DRIVER ICS



High-side and low-side drivers control two N-Channel MOSFETs or IGBTs in fast switching applications. The gate driver converts PWM input signals into gate-signals compatible to MOSFETs or IGBTs, providing a robust and efficient power semiconductor control. An integrated bootstrap circuit is generating a floating voltage with enables the high-side driver to operate up to 600V<sub>nc</sub>.

The drivers accept wide V<sub>DD</sub> supply voltage as well as wide logic input voltage ranges. Various built-in protection features ensure safe operation of the driver and the driven power semiconductors.

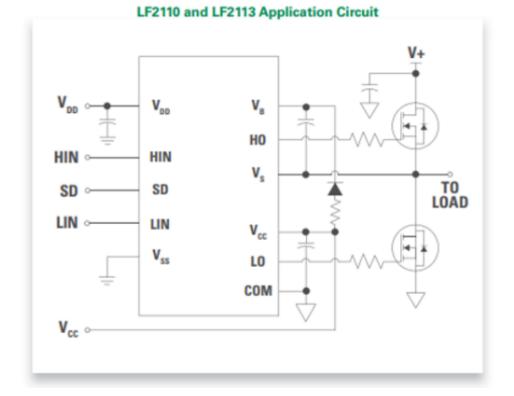
#### Features & Benefits

- High-side operation up to 600V<sub>pc</sub>
- Outputs tolerant to negative transients
- Supply voltage range: 10V to 20V
- Logic input voltage range: 3.3V to 20V
- Cycle-by-cycle edge-triggered shutdown circuitry
- Under Voltage Lockout (UVLO)
- Operating temperature range: -40°C to +125°C

### **Applications**

- DC-DC Converters
- AC-DC Inverters
- Motor Controls
  - Servo Motor Control
- Pumps and Fans
- Class D Power Amplifiers
- Uninterruptable Power Supplies (UPS)
- Welding
- Induction Cooking

Source: https://www.littelfuse.com







14-Pin SOIC



Do not hesitate to contact us

**ECOMAL Europe GmbH** 

Business Development technique@ecomal.com

# HALF-BRIDGE GATE DRIVER ICS



Half-bridge gate drivers control two N-Channel MOSFETs or IGBTs in fast switching applications. The gate driver converts PWM input signals into gate-signals compatible to MOSFETs or IGBTs, providing a robust and efficient power semiconductor control. An integrated bootstrap circuit is generating a floating voltage with enables the high-side driver to operate up to 600V<sub>DC</sub>.

The drivers accept wide V<sub>DD</sub> supply voltage as well as wide logic input voltage ranges. Various built-in protection features ensure safe operation of the driver and the driven power semiconductors.

### Features & Benefits

- High-side operation up to 600V<sub>pc</sub>
- Outputs tolerant to negative transients
- Supply voltage range: 10V to 20V
- Logic input voltage range: 3.3V to 20V
- Fixed or programmable deadtime
- Cycle-by-cycle edge-triggered shutdown circuitry
- Under Voltage Lockout (UVLO)
- Operating temperature range: -40°C to +125°C

## Applications

- Motor Controls / Drives
- Stepper Motor Drives
- DC/DC-Converters
- AC/DC-Inverters
- Robotics
- Cordless Power Tools
- Drones

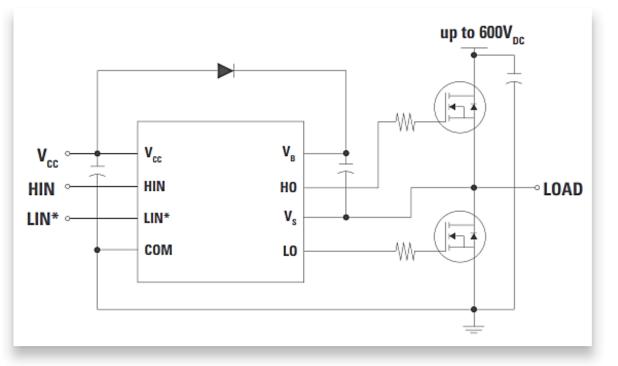


8-Pin SOIC



14-Pin SOIC

#### LF2103 Application Circuit



# 3-PHASE HALF-BRIDGE GATE DRIVER ICS



Switching three pairs of N-Channel MOSFETs or IGBTs in 6-pack configurations is a challenge in fast switching applications. 3-phase gate drivers convert PWM input signals into gate-signals compatible to MOSFETs or IGBTs, providing a robust and efficient power semiconductor control.

Integrated bootstrap circuits are generating floating voltages with enables the three high-side drivers to operate up to 600V<sub>DC</sub>.

The drivers accept wide V<sub>DD</sub> supply voltage as well as wide logic input voltage ranges. Various built-in protection features ensure safe operation of the driver and the driven power semiconductors.

### Features & Benefits

- High-side operation up to 600V<sub>nc</sub>
- Outputs tolerant to negative transients
- Supply voltage range: 10V to 20V
- Logic input voltage range: 3.3V to 20V
- Cycle-by-cycle edge-triggered shutdown circuitry
- Under Voltage Lockout (UVLO)
- Matched propagation delay times
- Cross conduction prevention logic
- Shoot-through protection logic
- Internal deadtime
- Operating temperature range: -40°C to +125°C

### **Applications**

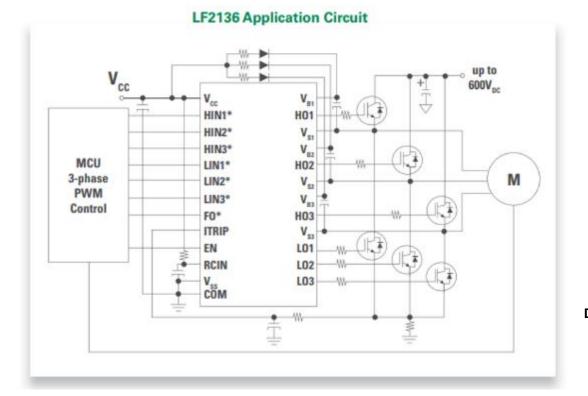
- 3-Phase Motor Drives
- White Goods
  - Pump Motors
  - Compressor Motors
  - Fan Motors
- Air Conditioners
- Cordless Power Tools
- Robotics



20-Pin SOIC



28-Pin SOIC



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